

TRANSMITTAL

Electronic Version v1.1

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Title of Invention	METHOD FOR SEPARATELY OPTIMIZING THIN GATE DIELECTRIC OF PMOS AND NMOS TRANSISTORS WITHIN THE SAME SEMICONDUCTOR CHIP AND DEVICE MANUFACTURED THEREBY							
Application Number : Date : First Named Applicant: Anthony I-Chih Chou Confirmation Number: Attorney Docket Number: FIS920030228US1								
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<table border="1"><tr><td>Submitted By:</td><td>Elec. Sign.</td><td>Sign. Capacity</td></tr><tr><td>H. Daniel Schnurmann Registered Number: 35791</td><td>H. Daniel Schnurmann /s/</td><td>Agent</td></tr></table>			Submitted By:	Elec. Sign.	Sign. Capacity	H. Daniel Schnurmann Registered Number: 35791	H. Daniel Schnurmann /s/	Agent
Submitted By:	Elec. Sign.	Sign. Capacity						
H. Daniel Schnurmann Registered Number: 35791	H. Daniel Schnurmann /s/	Agent						

Documents being submitted:	Files
us-fee-sheet	FIS920030228US1-usfees.xml us-fee-sheet.xsl us-fee-sheet.dtd
us-ids	FIS920030228US1-usidst.xml us-ids.dtd us-ids.xsl
us-request	FIS920030228US1-usrequ.xml us-request.dtd us-request.xsl
us-assignment	FIS920030228US1-usassn.xml us-assignment.xsl us-assignment.dtd FIS920030228US1Assignment1.tif FIS920030228US1Assignment2.tif FIS920030228US1Assignment3.tif
us-declaration	FIS920030228US1Declaration1.tif
application-body	FIS920030228US1-trans.xml us-application-body.xsl application-body.dtd wipo.ent mathml2.dtd mathml2-qname-1.mod isoamsa.ent isoamsb.ent isoamsc.ent isoamsn.ent isoamso.ent isoamsr.ent isogr3.ent isomfrk.ent isomopf.ent isomscr.ent isotech.ent isobox.ent isocyr1.ent isocyr2.ent isodia.ent isolat1.ent isolat2.ent isonum.ent isopub.ent mmlextra.ent mmlalias.ent soextblx.dtd FIS920030228US1Drawing1.tif FIS920030228US1Drawing2.tif FIS920030228US1Drawing3.tif FIS920030228US1Drawing4.tif FIS920030228US1Drawing5.tif

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us-declaration	FIS920030228US1Declaration2.tif
us-declaration	FIS920030228US1Declaration3.tif
us-declaration	FIS920030228US1Declaration4.tif
Comments	
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